



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Daijiro INOUE et al.**

Serial No.: **09/746,065**

RECEIVED
DEC -2 2002
Group Art Unit: 2828
EXAMINER CENTER 2800

Filed: **December 26, 2000**

Examiner: **Armando Rodriguez**

P.T.O. Confirmation No.: **1991**

For: **SEMICONDUCTOR LASER DEVICE**

AMENDMENT UNDER 37 C.F.R. §1.111

Commissioner for Patents
Washington, D.C. 20231

6# / am dt a
12/4/02
November 27, 2002
alBrown

Sir:

In response to the Office Action dated May 28, 2002, extended to November 28, 2002 by a three month Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

~~Please cancel claims 4 and 27 - 33 without prejudice or disclaimer.~~

Please amend claims 1, 2, 3, 5, 7, 17 and 24 as follows:

1. (Amended) A semiconductor laser device comprising:
an active layer;
a first cladding layer of a first conduction type provided on said active layer;
a current blocking layer of a second conduction type provided on said first cladding layer
except a current injection region;

a'